NSN 5962-00-760-2181

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View Online at https://aerobasegroup.com/nsn/5962-00-760-2181

Body Length:

Between 0.755 inches and 0.785 inches

Body Width:

Between 0.265 inches and 0.291 inches

Body Height:

Between 0.150 inches and 0.199 inches

Maximum Power Dissipation Rating:

512.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and w/enable and bipolar and wire-or outputs and positive outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

6 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

49956-461442 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Vaa damil/mli

Yes - demil/mli

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